

**Vishay Semiconductors** 

# High Power Infrared Emitting Diode, 850 nm, Surface Emitter Technology



## LINKS TO ADDITIONAL RESOURCES



## DESCRIPTION

As part of the <u>SurfLight</u><sup>™</sup> portfolio, the VSMA1085600 is an infrared, 850 nm emitting diode. It features a double stack emitter chip for highest radiant power. The 42 mil chip size allows 1.5 A DC operation and supports pulsed currents up to 5.0 A.

## **FEATURES**

- Package type: surface-mount
- · Package form: high power SMD with lens
- Dimensions (L x W x H in mm): 3.4 x 3.4 x 1.8
- Centroid wavelength:  $\lambda_{centroid} = 850 \text{ nm}$
- Angle of half intensity:  $\varphi = \pm 60^{\circ}$
- Designed for high drive currents: up to 1.5 A (DC) and up to 5 A (pulsed)

HALOGEN FREE <u>GREEN</u>

- Low thermal resistance: 6 K/W < R<sub>thJSP</sub> < 9 K/W</li> • ESD: up to 5 kV (according to ANSI / ESDA /
- JEDEC<sup>®</sup> JS-001)
- Floor life: 168 h, MSL 3, according to J-STD-020E
- Lead (Pb)-free reflow soldering
- · Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

### **APPLICATIONS**

- Driver and occupant monitoring
- Eve tracking
- · Safety and security, CCTV

PRODUCT SUMMARY					
COMPONENT	$I_e$ (mW/sr) at $I_F$ = 1.0 A	φ (°)	λ <sub>p</sub> (nm)	$\lambda_{\text{centroid}}$ (nm)	t <sub>r</sub> (ns)
VSMA1085600	490	± 60	860	850	10

### Note

Test conditions see table "Basic Characteristics"

ORDERING INFORMATION						
ORDERING CODE	PACKAGING	REMARKS	PACKAGE FORM			
VSMA1085600	Tape and reel	MOQ: 600 pcs, 600 pcs/reel	High power with lens			

### Note

MOQ: minimum order quantity



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ABSOLUTE MAXIMUM RATINGS (T <sub>amb</sub> = 25 °C, unless otherwise specified)					
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT	
Reverse voltage		V <sub>R</sub>	5	V	
Forward current		I <sub>F</sub>	1.5	А	
Surge forward current	t <sub>p</sub> = 100 μs	I <sub>FSM</sub>	5	А	
Power dissipation		Pv	5.33	W	
Junction temperature		Tj	145	°C	
Ambient temperature range		T <sub>amb</sub>	-40 to +125	°C	
Storage temperature range		T <sub>stg</sub>	-40 to +125	°C	
Soldering temperature	According to Fig. 11, J-STD-020E	T <sub>sd</sub>	260	°C	
Thermal resistance junction to solder point real <sup>(1)</sup>	JESD 51	R <sub>thJSP,real</sub>	6 to 9	K/W	
Thermal resistance junction to ambient real	JESD 51	R <sub>thJA,real</sub>	150	K/W	
ESD sensitivity	According to ANSI / ESDA / JEDEC JS-001	V <sub>ESD</sub>	5	kV	

Note

<sup>(1)</sup> Thermal resistance junction to solder point real has been measured with the part mounted on an ideal heatsink and the optical output power has been deducted from the total electrical power dissipation

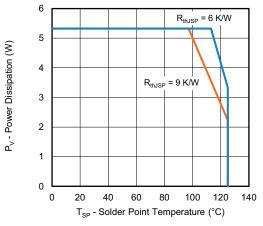


Fig. 1 - Power Dissipation Limit vs. Solder Point Temperature

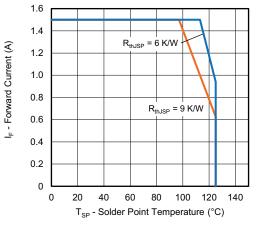


Fig. 2 - Forward Current Limit vs. Solder Point Temperature



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<b>BASIC CHARACTERISTICS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Forward voltage	$I_F = 0.35 \text{ A}, t_p = 10 \text{ ms}$	VF	2.7	2.95	3.1	V
	$I_F = 1 \text{ A}, t_p = 100 \ \mu \text{s}$	V <sub>F</sub>	2.8	3.1	3.3	V
	$I_F = 1.5 \text{ A}, t_p = 100 \ \mu \text{s}$	V <sub>F</sub>	2.9	3.25	3.55	V
	$I_F = 5 \text{ A}, t_p = 100 \ \mu \text{s}$	VF	3.2	3.9	4.4	V
Temperature coefficient of $V_F$	$I_F = 1 \text{ A}, t_p = 200 \ \mu \text{s}$		-	-2	-	mV/K
Reverse current		I <sub>R</sub>	Not designed for reverse operation $\mu A$			μA
Radiant intensity	$I_F = 0.35 \text{ A}, t_p = 10 \text{ ms}$	le	135	170	205	mW/sr
	$I_F = 1 \text{ A}, t_p = 100 \ \mu \text{s}$	l <sub>e</sub>	375	490	600	mW/sr
	I <sub>F</sub> = 1.5 A, t <sub>p</sub> = 100 μs	l <sub>e</sub>	515	715	915	mW/sr
	$I_F = 5 \text{ A}, t_p = 100 \ \mu \text{s}$	le	1550	2200	2850	mW/sr
Radiant power -	$I_F = 1 \text{ A}, t_p = 100 \ \mu \text{s}$	фе	-	1425	-	mW
	$I_F = 1.5 \text{ A}, t_p = 100 \ \mu \text{s}$	фе	-	2100	-	mW
Temperature coefficient of $\boldsymbol{\phi}$	I <sub>F</sub> = 1 A, t <sub>p</sub> = 200 μs	ΤK <sub>φ</sub>	-	-0.15	-	%/K
Angle of half intensity		φ	-	± 60	-	0
Peak wavelength	I <sub>F</sub> = 1 A, t <sub>p</sub> = 300 μs	λρ	-	860	-	nm
Centroid wavelength	I <sub>F</sub> = 1 A, t <sub>p</sub> = 300 μs	$\lambda_{centroid}$	-	850	-	nm
Spectral bandwidth	I <sub>F</sub> = 1 A, t <sub>p</sub> = 300 μs	Δλ	-	30	-	nm
Temperature coefficient of $\lambda_p$	$I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$	ΤΚ <sub>λp</sub>	-	0.25	-	nm/K
Rise time	I <sub>F</sub> = 1 A	tr	-	10	-	ns
Fall time	I <sub>F</sub> = 1 A	t <sub>f</sub>	-	15	-	ns

## BASIC CHARACTERISTICS (Tamb = 25 °C, unless otherwise specified)

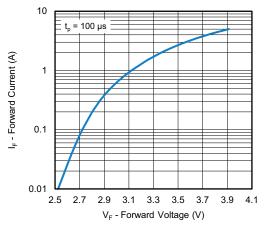


Fig. 3 - Forward Current vs. Forward Voltage

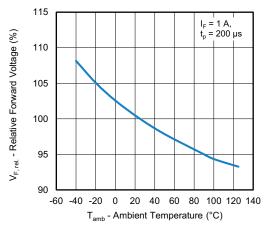


Fig. 4 - Relative Forward Voltage vs. Ambient Temperature

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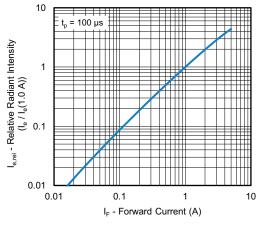


Fig. 5 - Relative Radiant Intensity vs. Forward Current

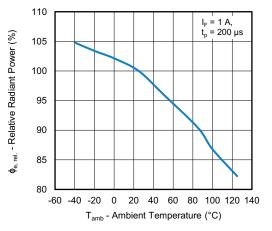


Fig. 6 - Relative Radiant Power vs. Ambient Temperature

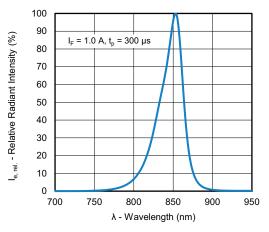


Fig. 7 - Relative Radiant Intensity vs. Wavelength

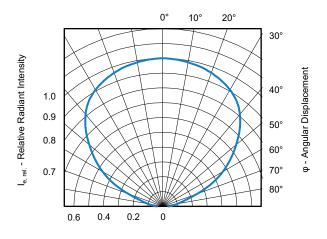


Fig. 8 - Relative Radiant Intensity vs. Angular Displacement

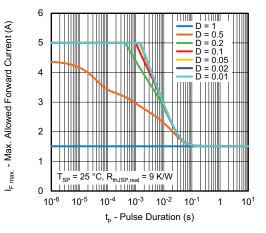


Fig. 9 - Max. Allowed Forward Current vs. Pulse Duration

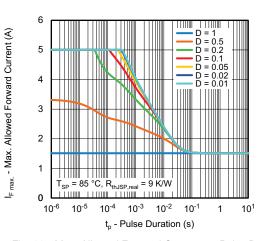


Fig. 10 - Max. Allowed Forward Current vs. Pulse Duration

Rev. 1.4, 08-Jul-2022

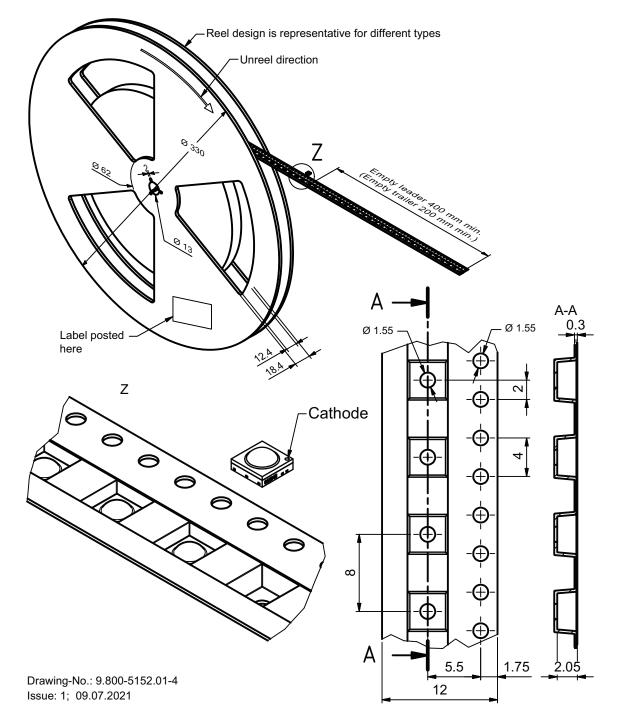
4 For technical questions, contact: <u>emittertechsupport@vishay.com</u>

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## TAPING DIMENSIONS in millimeters



#### Notes

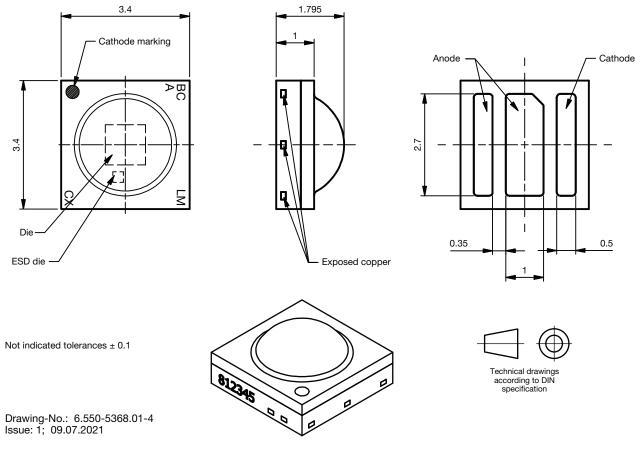
- · Empty component pockets sealed with top cover tape
- 7 inch reel 600 pieces per reel
- The maximum number of consecutive missing lamps is two
- In accordance with ANSI / EIA 481-1-A-1994 specifications





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### **PACKAGE DIMENSIONS** in millimeters



### Notes

- Tolerance is ± 0.10 mm (0.004") unless otherwise noted
- Specifications are subject to change without notice

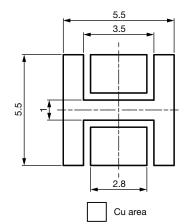
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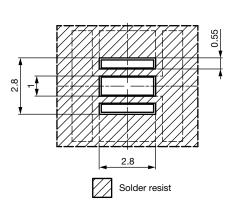
# **Vishay Semiconductors**

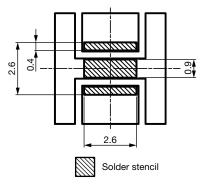
## **RECOMMENDED FOOTPRINT**

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ISHA







Drawing-No.: 6.550-5366.9-3 Issue: 1; 09.07.2021

## DRYPACK

Devices are packed in moisture barrier bags (MBB) to prevent the products from moisture absorption during transportation and storage. Each bag contains a desiccant.

## **FLOOR LIFE**

Floor life (time between soldering and removing from MBB) must not exceed the time indicated on MBB label:

Floor life: 168 h

Conditions: T<sub>amb</sub> < 30 °C, RH < 60 %

Moisture sensitivity level 3, according to J-STD-020E

## DRYING

In case of moisture absorption devices should be baked before soldering. Conditions see J-STD-033D or label. Devices taped on reel dry using recommended conditions 192 h at 40 °C (+ 5 °C), RH < 5 %.

#### 200 Max. 30 s 150 Max. 120 s Max. 100 s 100 Max. ramp down 6 °C/s 50 Max. ramp up 3 °C/s Max. 2 cycles allowed 0 100 0 50 150 200 250 300 Time (s) Fig. 11 - Lead (Pb)-free (Sn) Infrared Reflow Solder Profile According to J-STD-020E for Surface-Mount Components

Max. 260 °C

245 °C

Cathode marking

Component location on pad

SOLDER PROFILE

255 °C

240 °C

217 °C

300

250

Temperature (°C)

23192

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Revision: 01-Jan-2025

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